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Ultra-fast Plastic Rectifiers Reverse Voltage 400V to 600V

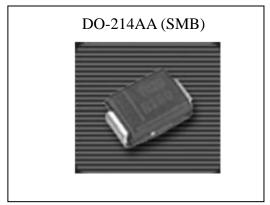
Forward Current 1A

MURS140 and MURS160

Features

- Glass passivated junction
- Plastic package has UL flammability classification 94V-0
- Ultra-fast recovery time for high efficiency
- Ideally suited for use in very high frequency switching power supplies, inverters, and as a free wheeling diode
- For surface mount applications
- High temperature soldering guaranteed: 250°C/10seconds on terminals

Outline



Mechanical Data

• Case: JEDEC DO-214AA(SMB) molded plastic body

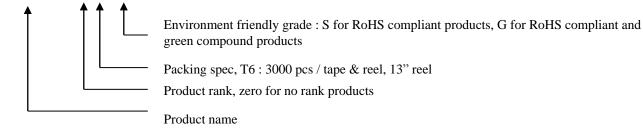
• Terminals: Pure tin plated, solderable per MIL-STD-750 method 2026

• Polarity: Color band denotes cathode end.

• Weight: 0.003 oz., 0.093 gram

Ordering Information

Device	Package	Shipping
MURS140- 0-T6-G	SMB	3000 pcs / Tape & Reel
MURS160- 0-T6-G	(Pb-free lead plating and halogen-free package)	3000 pcs / Tape & Reel





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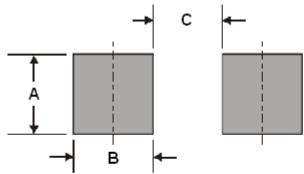
Maximum Ratings and Electrical Characteristics

(Rating at 25°C ambient temperature unless otherwise specified.)

Parameter		Symbol	Type		Units	
r diameter			MURS140	MURS160	Omis	
Maximum repetitive peak reverse voltage	Vrrm	400	600	V		
Peak reverse working voltage	Vrwm	400	600	V		
Maximum DC blocking voltage		VDC	400	600	V	
Maximum instantaneous forward voltage (Note 1) at 1 at 1	VF	1.25 1.05		V		
Maximum average forward rectified current (see Fig 1)	IF(AV)	1 2		A		
Peak forward surge current @8.3ms single half sine wave rated load (JEDEC method)	IFSM	35		A		
Maximum instantaneous reverse current at rated DC	TJ=25°C		5			
blocking voltage (Note 1)	TJ=100°C	IR	200		μΑ	
Maximum reverse recovery time at IF=0.5A, IR=1A,Irr=0.25A			50		ns	
Maximum reverse recovery time at I _F =1A, dI/dt=50A/μs, V _R =30V, I _T =10%I _{RM}			75		ns	
Maximum forward recovery time at I _F =1A, dI/dt=100A/μs, recovery to 1V			50		ns	
Typical thermal resistance, junction to ambient			13		°C/W	
Operating junction and storage temperature range			-55 ~ +175		$^{\circ}\!\mathbb{C}$	

Note: 1.Pulse test: pulse width \leq 300 μ s, duty cycle \leq 2%

Recommended Footprint



Dimensions in inches and (millimeter)

DIM	Inches	Millimeters		
	Тур	Тур		
Α	0.142	3.60		
В	0.059	1.50		
С	0.118	3.00		



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Characteristic Curves

Fig. 1 - Forward Current

Derating Curve

4.0

3.0

2.0

2.5

5.0

7.5

Lead Temperature(**C**)

Fig. 3 - Typical Instantaneous Forward Characteristics (MURS160)

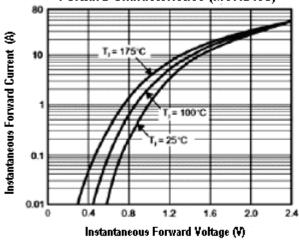


Fig. 5 - Typical Junction Capacitance

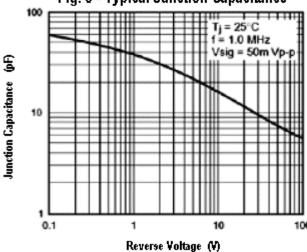


Fig. 2 - Maximum Non-Repetitive Peak

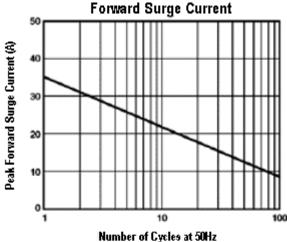
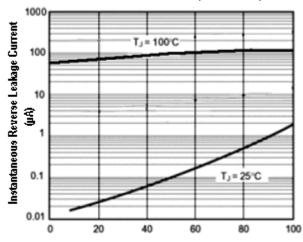


Fig. 4 - Typical Reverse Leakage Characteristics (MURS160)



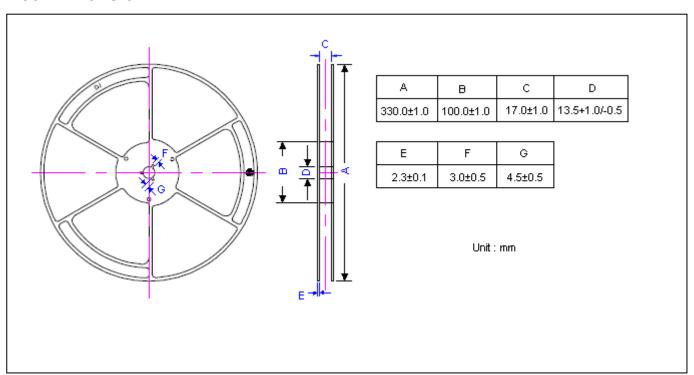
Percent of Rated Peak Reverse Voltage (%)



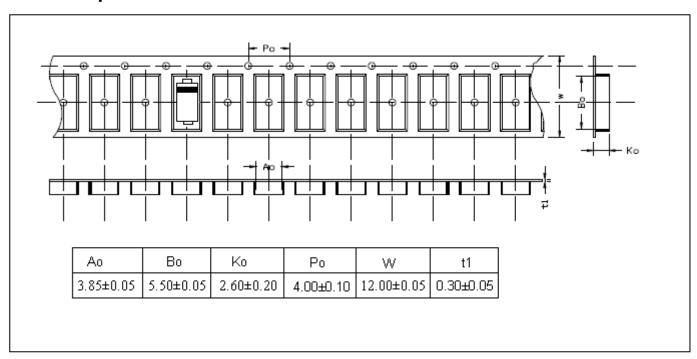
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Reel Dimension



Carrier Tape Dimension





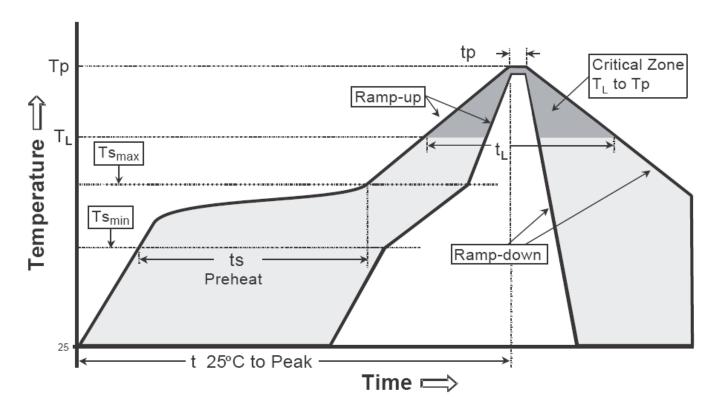
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Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly		
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.		
Preheat -Temperature Min(Ts min) -Temperature Max(Ts max) -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds		
Time maintained above: -Temperature (TL) - Time (tL)	183°C 60-150 seconds	217°C 60-150 seconds		
Peak Temperature(T _P) Time within 5°C of actual peak temperature(tp)	240 +0/-5 °C 10-30 seconds	260 +0/-5 °C 20-40 seconds		
Ramp down rate	6°C/second max.	6°C/second max.		
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.		

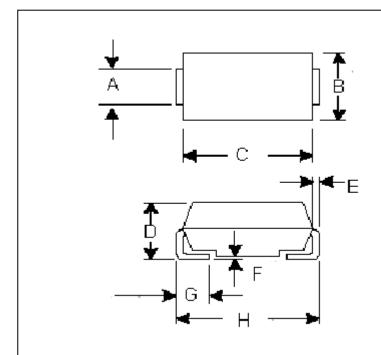
Note: All temperatures refer to topside of the package, measured on the package body surface.



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DO-214AA/SMB Dimension



DO-214AA/SMB Plastic Surface Mounted Package CYStek Package Code : SB

*:Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.	ואווט	Min.	Max.	Min.	Max.
Α	0.075	0.083	1.91	2.11	Е	0.006	0.012	0.15	0.31
В	0.130	0.155	3.30	3.94	F	0.002	0.008	0.05	0.20
С	0.154	0.185	3.90	4.70	G	0.035	0.056	0.90	1.41
D	0.078	0.103	1.99	2.61	Η	0.200	0.220	5.08	5.59

Notes: 1. Controlling dimension: millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material. 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

• Lead : Pure tin plated.

• Mold Compound : Epoxy resin family, flammability solid burning class:UL94V-0.

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